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Team Nexperia

High-speed switching diodes Rev. 8 — 18 March 2015

Product data sheet

#### 1. **Product profile**

### 1.1 General description

High-speed switching diodes, encapsulated in small Surface-Mounted Device (SMD) plastic packages.

#### Table 1. **Product overview**

Type number	Package			Package	Configuration
	NXP	JEITA	JEDEC	configuration	
BAV70	SOT23	-	TO-236AB	small	dual common cathode
BAV70M	SOT883	SC-101	-	leadless ultra small	dual common cathode
BAV70S	SOT363	SC-88	-	very small	quadruple common cathode/common cathode
BAV70T	SOT416	SC-75	-	ultra small	dual common cathode
BAV70W	SOT323	SC-70	-	very small	dual common cathode

• Low capacitance:  $C_d \le 1.5 \text{ pF}$ Reverse voltage:  $V_R \le 100 \text{ V}$ 

AEC-Q101 qualified

### 1.2 Features and benefits

- High switching speed:  $t_{rr} \le 4$  ns
- Low leakage current
- Small SMD plastic packages

### 1.3 Applications

- High-speed switching
- General-purpose switching

### 1.4 Quick reference data

#### Table 2. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per diode						1	
I <sub>R</sub>	reverse current	V <sub>R</sub> = 80 V		-	-	0.5	μA
V <sub>R</sub>	reverse voltage			-	-	100	V
t <sub>rr</sub>	reverse recovery time		[1]	-	-	4	ns

[1] When switched from I\_F = 10 mA to I\_R = 10 mA; R\_L = 100  $\Omega;$  measured at I\_R = 1 mA.



High-speed switching diodes

### 2. Pinning information

Table 3. Pi	nning		
Pin	Description	Simplified outline	Symbol
BAV70; BAV7	OT; BAV70W		-
1	anode (diode 1)		
2	anode (diode 2)	3	3
3	common cathode	2	1 2 006aab034
BAV70M	·		
1	anode (diode 1)		3
2	anode (diode 2)		
3	common cathode	2 Transparent top view	1 2 006aab034
BAV70S			
1	anode (diode 1)		
2	anode (diode 2)		6 5 4
3	common cathode (diode 3 and diode 4)	0	
4	anode (diode 3)		
5	anode (diode 4)		1 2 3
6	common cathode (diode 1 and diode 2)		006aab104

### 3. Ordering information

### Table 4. Ordering information

Tuno number	Deekere					
Type number Packag						
	Name	Description	Version			
BAV70	-	plastic surface-mounted package; 3 leads	SOT23			
BAV70M	SC-101	leadless ultra small plastic package; 3 solder lands; body 1.0 $\times$ 0.6 $\times$ 0.5 mm	SOT883			
BAV70S	SC-88	plastic surface-mounted package; 6 leads	SOT363			
BAV70T	SC-75	plastic surface-mounted package; 3 leads	SOT416			
BAV70W	SC-70	plastic surface-mounted package; 3 leads	SOT323			

### 4. Marking

Table 5.         Marking codes	
Type number	Marking code <sup>[1]</sup>
BAV70	A4*
BAV70M	S4
BAV70S	A4*
BAV70T	A4
BAV70W	A4*

[1] \* = -: made in Hong Kong

\* = p: made in Hong Kong

\* = t: made in Malaysia

\* = W: made in China

### 5. Limiting values

#### Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode				I	
V <sub>RRM</sub>	repetitive peak reverse voltage		-	100	V
V <sub>R</sub>	reverse voltage	reverse voltage -		100	V
l <sub>F</sub>	forward current				
	BAV70	$T_{amb} \le 25 \ ^{\circ}C$	-	215	mA
	BAV70M	T <sub>s</sub> = 90 °C	-	150	mA
	BAV70S	T <sub>s</sub> = 60 °C	-	250	mA
	BAV70T	T <sub>s</sub> = 90 °C	-	150	mA
	BAV70W	$T_{amb} \le 25 \ ^{\circ}C$	-	175	mA
I <sub>FRM</sub>	repetitive peak forward current				
	BAV70		-	450	mA
	BAV70M		-	500	mA
	BAV70S		-	450	mA
	BAV70T		-	500	mA
	BAV70W		-	500	mA
I <sub>FSM</sub>	non-repetitive peak forward	square wave	[1]		
	current	t <sub>p</sub> = 1 μs	-	4	А
		t <sub>p</sub> = 1 ms	-	1	А
		t <sub>p</sub> = 1 s	-	0.5	А

#### High-speed switching diodes

Symbol	Parameter	Parameter Conditions		Max	Unit
P <sub>tot</sub>	total power dissipation		[2]		
	BAV70	$T_{amb} \le 25 \ ^{\circ}C$	-	250	mW
	BAV70M	$T_{amb} \le 25 \ ^{\circ}C$	[3] -	250	mW
	BAV70S	T <sub>s</sub> = 60 °C	-	350	mW
	BAV70T	T <sub>s</sub> = 90 °C	-	170	mW
	BAV70W	$T_{amb} \le 25 \ ^{\circ}C$	-	200	mW
Per device	)				
I <sub>F</sub>	forward current				
	BAV70	$T_{amb} \le 25 \ ^{\circ}C$	-	125	mA
	BAV70M	T <sub>s</sub> = 90 °C	-	75	mA
	BAV70S	$T_s = 60 \ ^{\circ}C$	-	100	mA
	BAV70T	T <sub>s</sub> = 90 °C	-	75	mA
	BAV70W	$T_{amb} \le 25 \ ^{\circ}C$	-	100	mA
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

#### Table 6. Limiting values ...continued

n accordance with the Absolute Maximum Rating System (IEC 60134).

[1]  $T_i = 25 \circ C$  prior to surge.

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[3] Reflow soldering is the only recommended soldering method.

### 6. Thermal characteristics

#### Table 7.Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per diode							
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1]				
	BAV70			-	-	500	K/W
	BAV70M		[2]	-	-	500	K/W
	BAV70W			-	-	625	K/W
R <sub>th(j-t)</sub>	thermal resistance from junction to tie-point						
	BAV70			-	-	360	K/W
	BAV70W			-	-	300	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point						
	BAV70S			-	-	255	K/W
	BAV70T			-	-	350	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

BAV70\_SER

### 7. Characteristics

Table 8.

$T_{amb} = 25 \ ^{\circ}C$ unless otherwise specified.						
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
V <sub>F</sub>	forward voltage	[1]				
		I <sub>F</sub> = 1 mA	-	-	715	mV
		I <sub>F</sub> = 10 mA	-	-	855	mV
		I <sub>F</sub> = 50 mA	-	-	1	V
		I <sub>F</sub> = 150 mA	-	-	1.25	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 25 V	-	-	30	nA
		V <sub>R</sub> = 80 V	-	-	0.5	μA
		$V_R = 25 V; T_j = 150 °C$	-	-	30	μA
		$V_R = 80 V; T_j = 150 °C$	-	-	100	μA
C <sub>d</sub>	diode capacitance	V <sub>R</sub> = 0 V; f = 1 MHz	-	-	1.5	pF
t <sub>rr</sub>	reverse recovery time	[2]	-	-	4	ns
V <sub>FR</sub>	forward recovery voltage	[3]	-	-	1.75	V

 $\label{eq:point} \begin{tabular}{ll} \end{tabular} \end{tabular} \begin{tabular}{ll} \end{tabular} 1 \end{tabular} \end{tabular} \end{tabular} \begin{tabular}{ll} \end{tabular} \end{tabular} \end{tabular} \end{tabular} \begin{tabular}{ll} \end{tabular} \end{tabular}$ 

[2] When switched from I\_F = 10 mA to I\_R = 10 mA; R\_L = 100  $\Omega$ ; measured at I\_R = 1 mA.

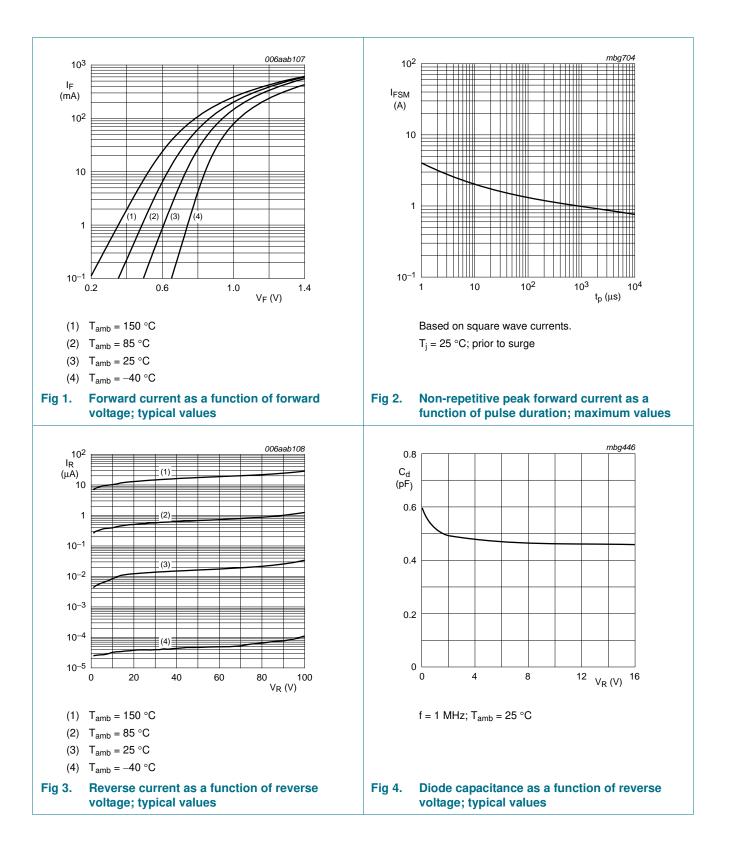
[3] When switched from  $I_F = 10 \text{ mA}$ ;  $t_r = 20 \text{ ns}$ .

**Characteristics** 

### **NXP Semiconductors**

## **BAV70 series**

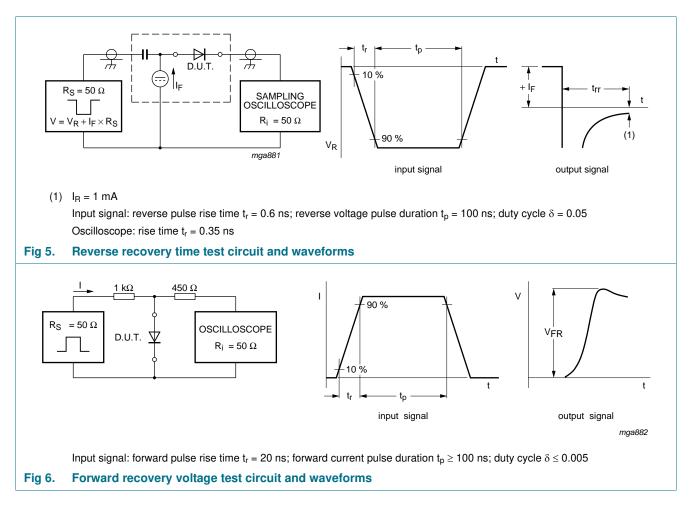
**High-speed switching diodes** 



BAV70 SER

High-speed switching diodes

### 8. Test information

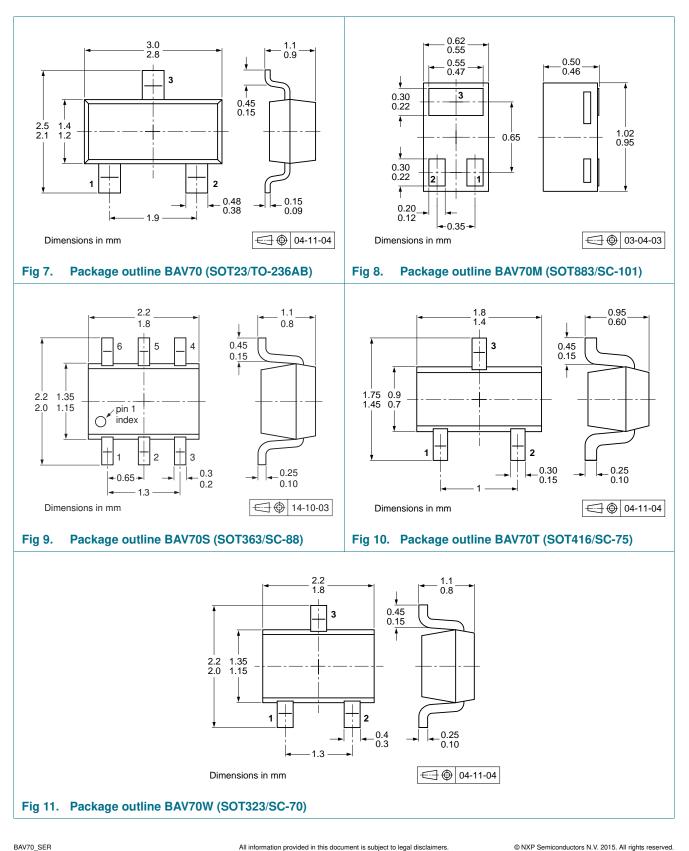


### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

**High-speed switching diodes** 

#### **Package outline** 9.



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High-speed switching diodes

### **10. Packing information**

#### Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

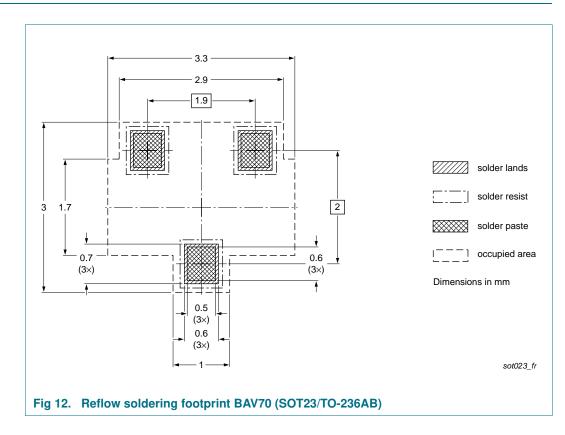
Type number	Package	Description	Packing q	uantity
			3000	10000
BAV70	SOT23	4 mm pitch, 8 mm tape and reel -21		-235
BAV70M	SOT883	2 mm pitch, 8 mm tape and reel		-315
BAV70S	SOT363	4 mm pitch, 8 mm tape and reel; T1 [2]	-115	-135
		4 mm pitch, 8 mm tape and reel; T2 [3]	-125	-165
BAV70T	SOT416	4 mm pitch, 8 mm tape and reel -115		-135
BAV70W	SOT323	4 mm pitch, 8 mm tape and reel	-115	-135

[1] For further information and the availability of packing methods, see <u>Section 14</u>.

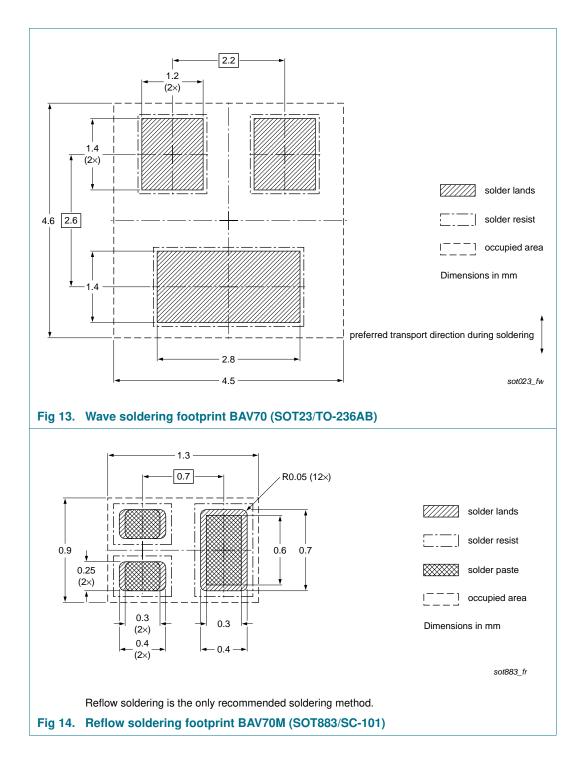
[2] T1: normal taping

[3] T2: reverse taping

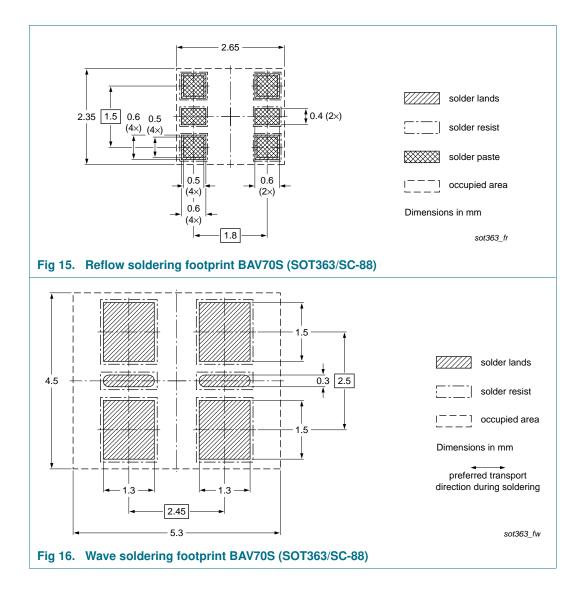
### 11. Soldering



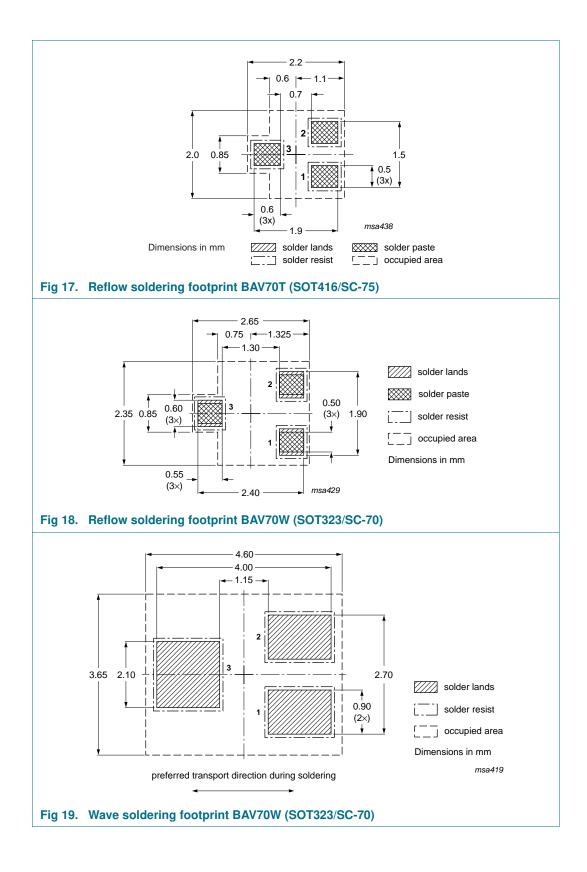
### High-speed switching diodes



High-speed switching diodes



**High-speed switching diodes** 



### 12. Revision history

Table 10. Revision history					
Document ID	Release date	Data sheet status	Change notice	Supersedes	
BAV70_SER v.8	20150318	Product data sheet	-	BAV70_SER_7	
Modifications:		t of this data sheet has been of NXP Semiconductors.	redesigned to comply w	vith the new identity	
	<ul> <li>Legal texts</li> </ul>	s have been adapted to the ne	ew company name whe	ere appropriate.	
BAV70_SER_7	20071127	Product data sheet	-	BAV70_6 BAV70S_2 BAV70T_3 BAV70W_6	
BAV70_6	20020403	Product specification	-	BAV70_5	
BAV70S_2	19971021	Product specification	-	BAV70S_1	
BAV70T_3	20040204	Product specification	-	BAV70T_2	
BAV70W_6	20020405	Product specification	-	BAV70W_5	

### 13. Legal information

### 13.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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#### High-speed switching diodes

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#### High-speed switching diodes

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